



APTM120A20DG Information

Heisener.com

For Reference Only

Part Number APTM120A20DG

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 1200V 50A SP6

Package SP6

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









APTM120A20DG Specifications

	Report errors?
Supplier Device Package	SP6
Package / Case	SP6
Mounting Type	Chassis Mount
Operating Temperature	-40°C ~ 150°C (TJ)
Power - Max	1250W
Input Capacitance (Ciss) (Max) @ Vds	15200pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	600nC @ 10V
Vgs(th) (Max) @ Id	5V @ 6mA
Rds On (Max) @ Id, Vgs	240 mOhm @ 25A, 10V
Current - Continuous Drain (Id) @ 25°C	50A
Drain to Source Voltage (Vdss)	1200V (1.2kV)
FET Feature	Standard
FET Type	2 N-Channel (Half Bridge)
Series	-
Package	SP6
	Transistors - FETs, MOSFETs - Arrays
Category	Discrete Semiconductor Products
Manufacturer	Microsemi Corporation
Manufacturer Part Number	APTM120A20DG

APTM120A20DG Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

APTM120A20DG Payment Methods

































If you have any question about APTM120A20DG, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com